

MT41K256M16V90BWC1



Part Number: MT41K256M16V90BWC1

Manufacturer: Micron Technology

Description: IC DRAM 4G PARALLEL DIE

Data sheet:

RoHS Status: Lead free / RoHS Compliant

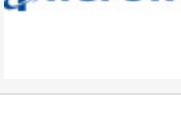
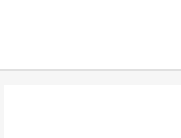
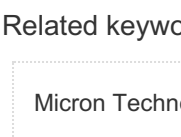
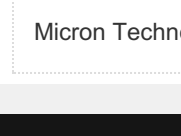
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PRODUCT PARAMETER			
Part Number	MT41K256M16V90BWC1	Manufacturer	Micron Technology
Description	IC DRAM 4G PARALLEL DIE	Lead Free Status / RoHS Status	Lead free / RoHS Compliant
Quantity Available	9153 pcs	Data sheet	
Category	Integrated Circuits (ICs)	Write Cycle Time - Word, Page	-
Voltage - Supply	1.283 V ~ 1.45 V	Technology	SDRAM - DDR3L
Series	-	Operating Temperature	0°C ~ 95°C (TC)
Moisture Sensitivity Level (MSL)	3 (168 Hours)	Memory Type	Volatile
Memory Size	4Gb (256M x 16)	Memory Interface	Parallel
Memory Format	DRAM	Lead Free Status / RoHS Status	Lead free / RoHS Compliant
Detailed Description	SDRAM - DDR3L Memory IC 4Gb (256M x 16) Parallel		
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